LDO Regulator - Adjustable Current Limit, 3.3 V Logic

5 V to 20 V

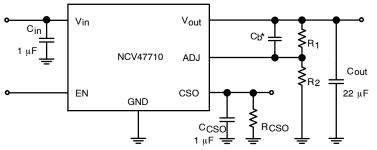
The NCV47710 is a 350 mA output current integrated low dropout regulator designed for use in harsh automotive environments. It includes wide operating temperature and input voltage ranges. The device is offered with adjustable voltage versions available in 6% output voltage accuracy. It has a high peak input voltage tolerance and reverse input voltage protection. It also provides overcurrent protection, overtemperature protection and enable for control of the state of the output voltage. The integrated current sense feature provides diagnosis and system protection functionality. The current limit of the device is adjustable by resistor connected to CSO pin. Voltage on CSO pin is proportional to output current.

Features

- Adjustable Voltage Version (from 5 V to 20 V) ± 6% Output Voltage for ±3% Output Voltage Accuracy see NCV47711 Specification
- Enable Input (3.3 V Logic Compatible Thresholds) for 5 V Logic Compatible Thresholds see NCV47700 or NCV47701 Specification
- Adjustable Current Limit (from 10 mA to 350 mA) with 10% accuracy
- Protection Features:
 - Current Limitation
 - Thermal Shutdown
 - Reverse Input Voltage
- This is a Pb–Free Device

Typical Applications

- Audio and Infotainment System
- Instrument Cluster
- Navigation
- Satellite Radio



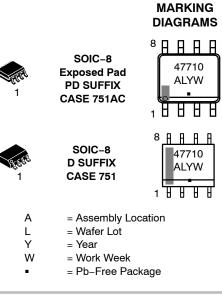
*Required if usage of low ESR output capacitor C_{out} is demand, see Regulator Stability Considerations section.

Figure 1. Application Schematic

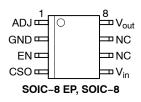


ON Semiconductor®

www.onsemi.com

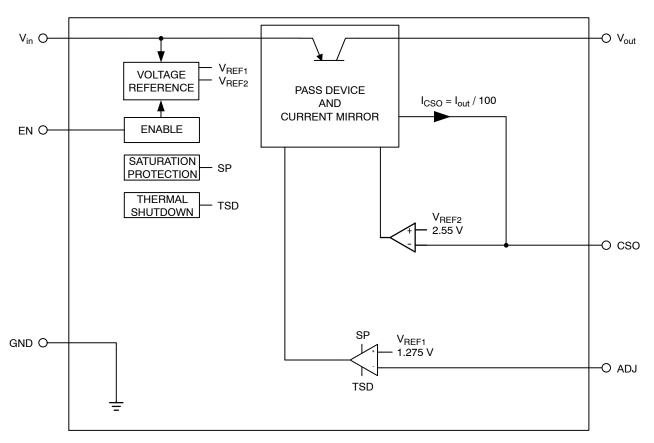






ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.





PIN FUNCTION DESCRIPTION

Pin No. SOIC-8 EP	Pin No. SOIC-8	Pin Name	Description
1	1	ADJ	Adjustable Voltage Setting Input. See Application Section for more details.
2	2	GND	Power Supply Ground.
3	3	EN	Enable Input; low level disables the IC.
4	4	CSO	Current Sense Output, Current Limit setting and Output Current value information. See Application Section for more details.
5	5	V _{in}	Positive Power Supply Input.
6	6	NC	Not Connected
7	7	NC	Not Connected
8	8	V _{out}	Regulated Output Voltage.
EPAD	-	EPAD	Connect to ground potential or leave unconnected.

ABSOLUTE MAXIMUM RATINGS (Note 1)

Rating	Symbol	Min	Max	Unit
Input Voltage	V _{in}	-42	45	V
Enable Input Voltage	V _{EN}	-0.3	7.0	V
Adjustable Input Voltage	V _{ADJ}	-0.3	10	V
CSO Voltage	V _{CSO}	-0.3	7.0	V
Output Voltage	V _{out}	-1	40	V
Junction Temperature	Τ _J	-40	150	°C
Storage Temperature	T _{STG}	-55	150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

ESD CAPABILITY (Note 2)

Rating	Symbol	Min	Max	Unit
ESD Capability, Human Body Model	ESD _{HBM}	-2	2	kV
ESD Capability, Machine Model	ESD _{MM}	-200	200	V

This device series incorporates ESD protection and is tested by the following methods: ESD Human Body Model tested per AEC-Q100-002 (JS-001-2010)

ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)

Field Induced Charge Device Model ESD characterization is not performed on plastic molded packages with body sizes < 50mm² due to the inability of a small package body to acquire and retain enough charge to meet the minimum CDM discharge current waveform characteristic defined in JEDEC JS-002-2014.

LEAD SOLDERING TEMPERATURE AND MSL (Note 3)

Rating		Symbol	Min	Max	Unit
Moisture Sensitivity Level	SOIC-8 EP SOIC-8	MSL	2	2	-

3. For more information, please refer to our Soldering and Mounting Techniques Reference Manual, SOLDERRM/D

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics, SOIC-8 EP (single layer PCB) Thermal Resistance, Junction-to-Air (Note 4) Thermal Reference, Junction-to-Lead (Note 4)	R _{0JA} R _{ψJL}	70 19	°C/W
Thermal Characteristics, SOIC-8 EP (4 layers PCB) Thermal Resistance, Junction-to-Air (Note 4) Thermal Reference, Junction-to-Lead (Note 4)	R _{θJA} R _{ψJL}	29 12	°C/W
Thermal Characteristics, SOIC-8 (single layer PCB) Thermal Resistance, Junction-to-Air (Note 4) Thermal Reference, Junction-to-Lead (Note 4)	R _{θJA} R _{ψJL}	121 42	°C/W
Thermal Characteristics, SOIC-8 (4 layers PCB) Thermal Resistance, Junction-to-Air (Note 4) Thermal Reference, Junction-to-Lead (Note 4)	R _{θJA} R _{ψJL}	77 52	°C/W

4. Values based on copper area of 645 mm² (or 1 in²) of 1 oz copper thickness and FR4 PCB substrate. Single layer – according to JEDEC51.3, 4 layers - according to JEDEC51.7.

RECOMMENDED OPERATING RANGES

Rating	Symbol	Min	Max	Unit
Input Voltage (Note 5)	V _{in}	5.5	40	V
Output Current Limit (Note 6)	I _{LIM}	10	350	mA
Junction Temperature	Τ _J	-40	150	°C
Nominal Output Voltage	V _{out_nom}	5.0	20	V
Current Sense Output (CSO) Capacitor	C _{CSO}	1.0	4.7	μF

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

5. Minimum $V_{in} = 5.5 \text{ V or } (V_{out nom} + 0.5 \text{ V})$, whichever is higher. 6. Corresponding R_{CSO} is in range from 25 k Ω down to 728 Ω .

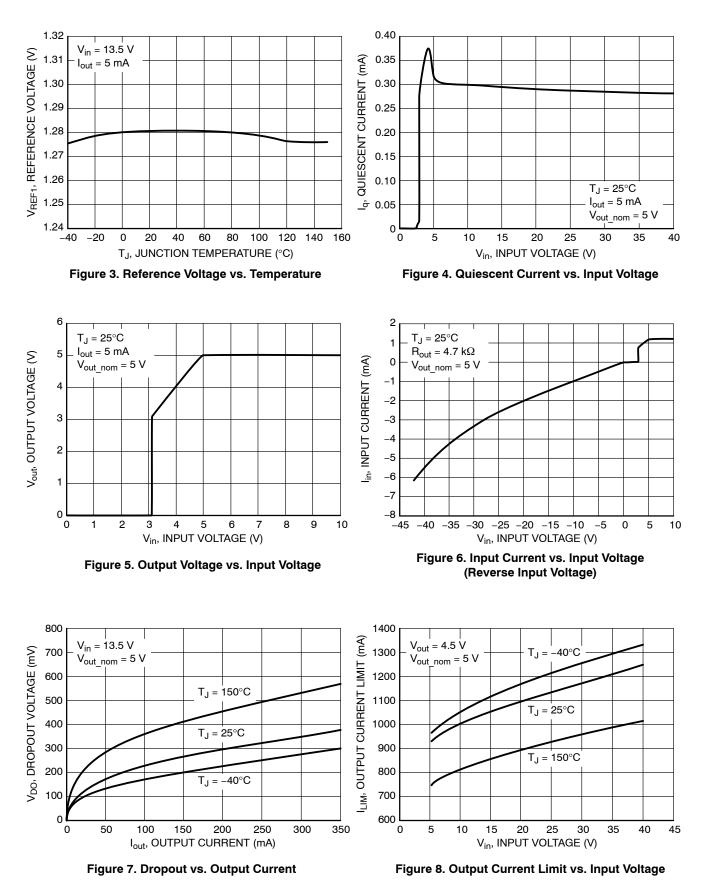
ELECTRICAL CHARACTERISTICS V_{in} = 13.5 V, V_{EN} = 3.3 V, R_{CSO} = 0 Ω , C_{CSO} = 1 μ F, C_{in} = 1 μ F, C_{out} = 22 μ F, ESR = 1.5 Ω , Min and Max values are valid for temperature range -40° C \leq T_J \leq 150°C unless otherwise noted and are guaranteed by test design or statistical correlation. Typical values are referenced to T_J = 25°C.

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
REGULATOR OUTPUT						
Output Voltage (Accuracy %)	$V_{in} = (V_{out_nom} + 1 V)$ to 40 V, $I_{out} = 5 mA$ to 350 mA	V _{out}	-6	-	6	%
Line Regulation	$V_{in} = (V_{out_nom} + 1 V)$ to $(V_{out_nom} + 20V)$, $I_{out} = 5mA$	Reg _{line}	-	0.1	2.0	%
Load Regulation	I _{out} = 5 mA to 350 mA	Reg _{load}	-	0.14	2.8	%
Dropout Voltage (Note 7)	I_{out} = 150 mA, $V_{DO} = V_{in} - V_{out}$	V _{DO}	-	250	500	mV
DISABLE AND QUIESCENT CUR	RENTS					
Disable Current $V_{EN} = 0 V$ $V_{EN} = 0 V$, $T_J = 25^{\circ}C$		I _{DIS}	-	_ 85	10 -	μA nA
Quiescent Current, I _q = I _{in} – I _{out}	$I_{out} = 1 \text{ mA}, V_{in} = (V_{out_nom} + 8.5 \text{ V})$	۱ _q	-	150	230	μA
Quiescent Current, I _q = I _{in} – I _{out}	$I_{out} = 350 \text{ mA}, V_{in} = (V_{out_nom} + 8.5 \text{ V})$	۱ _q	-	23	50	mA
CURRENT LIMIT PROTECTION						-
Current Limit	$V_{out} = 0.9 \text{ x } V_{out_nom}, V_{in} = (V_{out_nom} + 8.5 \text{ V})$	I _{LIM}	400	-	-	mA
PSRR & NOISE						-
Power Supply Ripple Rejection	f = 100 Hz, 0.5 V_{p-p} , I_{out} = 5 mA, C_{in} = none	PSRR	-	70	-	dB
Output Noise Voltage	f = 10 Hz to 100 kHz, C_b = 10 nF, I_{out} = 5 mA	Vn	-	100	-	μV_{rms}
ENABLE						
Enable Input Threshold Voltage Logic Low (OFF) Logic High (ON)	$V_{out} \le 0.1 V$ $V_{out} \ge 0.9 \times V_{out_nom}$	V _{th(EN)}	0.99 –	1.85 1.9	_ 2.31	V
Enable Input Current	V _{EN} = 3.3 V	I _{EN}	2.0	9.0	20	μA
Turn On Time from Enable ON to 90% of V _{out_nom}	I_{out} = 100 mA, C _b = 10 nF, R ₁ = 82 kΩ, R ₂ = 27 kΩ	t _{on}	_	1.6	-	ms
OUTPUT CURRENT SENSE						
CSO Voltage Level at Current Limit		V _{CSO_Ilim}	2.346 (-8 %)	2.55	2.754 (+8 %)	V
CSO Transient Voltage Level	C_{CSO} = 4.7 $\mu F,~R_{CSO}$ = 1 kΩ, I_{out} pulse from 10 mA to 350 mA, t_r = 1 μs	V _{CSO}	-	-	3.0	V
CSO Current to Output Current Ratio (Note 8)	$V_{CSO} = 2 \text{ V}, \text{ I}_{out} = 10 \text{ mA to } 350 \text{ mA}, (V_{out_nom} = 5\text{V})$	I _{CSO} /I _{out}	_ (-10%)	(1/100)	_ (+10%)	-
CSO Current at No Load Current	$V_{CSO} = 0 \text{ V}, \text{ I}_{out} = 0 \text{ mA}, (V_{out_nom} = 5 \text{ V})$	I _{CSO_off}	_	-	10	μA
REVERSE CURRENT						
Reverse Current (Note 9)	V _{in} = 12 V, V _{out} = 14 V	I _{out_rev}	-40	-25	-	mA
THERMAL SHUTDOWN						
Thermal Shutdown Temperature	l _{out} = 5 mA	T _{SD}	150	_	195	°C

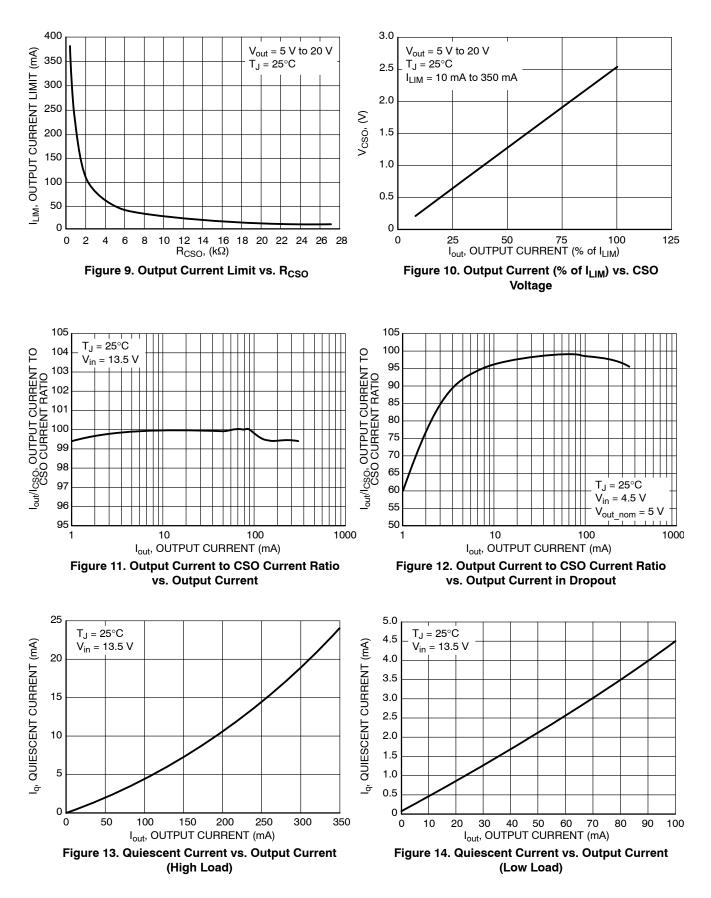
7. Measured when the output voltage V_{out} has dropped –2% from the nominal value obtained at $V_{in} = V_{out_nom} + 8.5$ V. 8. Not guaranteed in dropout.

9. Values based on design and/or characterization.

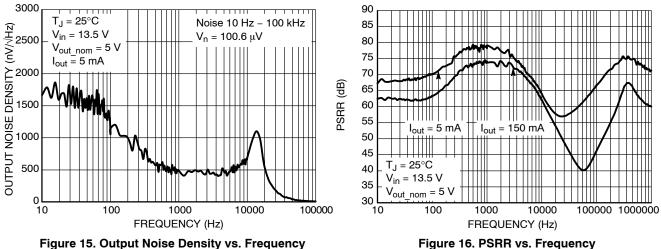
TYPICAL CHARACTERISTICS



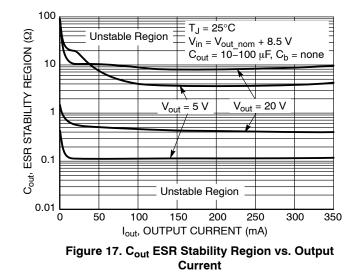
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS







DEFINITIONS

General

All measurements are performed using short pulse low duty cycle techniques to maintain junction temperature as close as possible to ambient temperature.

Output Voltage

The output voltage parameter is defined for specific temperature, input voltage and output current values or specified over Line, Load and Temperature ranges.

Line Regulation

The change in output voltage for a change in input voltage measured for specific output current over operating ambient temperature range.

Load Regulation

The change in output voltage for a change in output current measured for specific input voltage over operating ambient temperature range.

Dropout Voltage

The input to output differential at which the regulator output no longer maintains regulation against further reductions in input voltage. It is measured when the output voltage V_{out} has dropped -2% from the nominal value obtained at $V_{in} = V_{out_nom} + 8.5$ V. The junction temperature, load current, and minimum input supply requirements affect the dropout level.

Quiescent and Disable Currents

Quiescent Current (I_q) is the difference between the input current (measured through the LDO input pin) and the output load current. If Enable pin is set to LOW the regulator

reduces its internal bias and shuts off the output, this term is called the disable current (I_{DIS}).

Current Limit

Current Limit is value of output current by which output voltage drops below 90% of its nominal value.

PSRR

Power Supply Rejection Ratio is defined as ratio of output voltage and input voltage ripple. It is measured in decibels (dB).

Line Transient Response

Typical output voltage overshoot and undershoot response when the input voltage is excited with a given slope.

Load Transient Response

Typical output voltage overshoot and undershoot response when the output current is excited with a given slope between low–load and high–load conditions.

Thermal Protection

Internal thermal shutdown circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated at typically 175°C, the regulator turns off. This feature is provided to prevent failures from accidental overheating.

Maximum Package Power Dissipation

The power dissipation level is maximum allowed power dissipation for particular package or power dissipation at which the junction temperature reaches its maximum operating value, whichever is lower.

APPLICATIONS INFORMATION

Circuit Description

The NCV47710 is an integrated low dropout regulator that provides a regulated voltage at 350 mA to the output. It is enabled with an input to the enable pin. The regulator voltage is provided by a PNP pass transistor controlled by an error amplifier with a bandgap reference, which gives it the lowest possible dropout voltage. The output current capability is 350 mA, and the base drive quiescent current is controlled to prevent oversaturation when the input voltage is low or when the output is overloaded. The integrated current sense feature provides diagnosis and system protection functionality. The current limit of the device is adjustable by resistor connected to CSO pin. Voltage on CSO pin is proportional to output current. The regulator is protected by both current limit and thermal shutdown. Thermal shutdown occurs above 150°C to protect the IC during overloads and extreme ambient temperatures.

Regulator

The error amplifier compares the reference voltage to a sample of the output voltage (V_{out}) and drives the base of a PNP series pass transistor via a buffer. The reference is a bandgap design to give it a temperature–stable output. Saturation control of the PNP is a function of the load current and input voltage. Oversaturation of the output power device is prevented, and quiescent current in the ground pin is minimized.

Regulator Stability Considerations

The input capacitor (Cin) is necessary to stabilize the input impedance to avoid voltage line influences. The output capacitor (Cout) helps determine three main characteristics of a linear regulator: startup delay, load transient response and loop stability. The capacitor value and type should be based on cost, availability, size and temperature constraints. The aluminum electrolytic capacitor is the least expensive solution, but, if the circuit operates at low temperatures $(-25^{\circ}C \text{ to } -40^{\circ}C)$, both the value and ESR of the capacitor will vary considerably. The capacitor manufacturer's data sheet usually provides this information. The value for the output capacitor Cout, shown in Figure 1 should work for most applications; see also Figure 17 for output stability at various load and Output Capacitor ESR conditions. Stable region of ESR in Figure 17 shows ESR values at which the LDO output voltage does not have any permanent oscillations at any dynamic changes of output load current. Marginal ESR is the value at which the output voltage waving is fully damped during four periods after the load change and no oscillation is further observable.

ESR characteristics were measured with ceramic capacitors and additional series resistors to emulate ESR. Low duty cycle pulse load current technique has been used to maintain junction temperature close to ambient temperature.

Calculating Bypass Capacitor

If usage of low ESR ceramic capacitors is demanded, connect the bypass capacitor C_b between Adjustable Input pin and V_{out} pin according to Applications circuit at Figure 1. Parallel combination of bypass capacitor C_b with the feedback resistor R_1 contributes in the device transfer function as an additional zero and affects the device loop stability, therefore its value must be optimized. Attention to the Output Capacitor value and its ESR must be paid. See also Stability in High Speed Linear LDO Regulators Application Note, AND8037/D for more information. Optimal value of bypass capacitor is given by following expression:

$$C_{b} = \frac{1}{2 \times \pi \times f_{z} \times R_{1}}$$
 (eq. 1)

where

R1 - the upper feedback resistor

 f_z – the frequency of the zero added into the device transfer function by R_1 and C_b external components.

Set the R_1 resistor according to output voltage requirement. Chose the f_z with regard on the output capacitance C_{out} , refer to the table below.

C _{out} (μF)	10	22	47	100
f _Z range (kHz)	3.3-48.2	1.5–33	1.5–33	2.2–22

Ceramic capacitors and its part numbers listed bellow have been used as low ESR output capacitors C_{out} from the table above to define the frequency ranges of additional zero required for stability:

GRM31CR71C106KAC7 (10 μF, 16 V, X7R, 1206) GRM32ER71C226KE18 (22 μF, 16 V, X7R, 1210) GRM32ER61C476ME15 (47 μF, 16 V, X5R, 1210) GRM32ER60J107ME20 (100 μF, 6.3 V, X5R, 1210)

Enable Input

The enable pin is used to turn the regulator on or off. By holding the pin down to a voltage less than 0.99 V, the output of the regulator will be turned off. When the voltage on the enable pin is greater than 2.31 V, the output of the regulator will be enabled to power its output to the regulated output voltage.

Setting the Output Voltage

The output voltage range can be set between 5 V and 20 V. This is accomplished with an external resistor divider feeding back the voltage to the IC back to the error amplifier by the voltage adjust pin ADJ. The internal reference voltage is set to a temperature stable reference (V_{REF1}) of 1.275 V. The output voltage is calculated from the following formula. Ignoring the bias current into the ADJ pin:

$$V_{out} = V_{REF1} \left(1 + \frac{R_1}{R_2} \right) \qquad (eq. 2)$$

Use $R_2 < 50 \text{ k}\Omega$ to avoid significant voltage output errors due to ADJ bias current.

Designers should consider the tolerance of R₁ and R₂ during the design phase.

Setting the Output Current Limit

The output current limit can be set between 10 mA and 350 mA by external resistor R_{CSO} (see Figure 1). Capacitor C_{CSO} of 1 μ F in parallel with R_{CSO} is required for stability of current limit control circuitry (see Figure 1).

$$V_{CSO} = I_{out} \left(R_{CSO} \times \frac{1}{100} \right)$$
 (eq. 3)

$$I_{\text{LIM}} = \frac{100}{1} \times \frac{2.55}{\text{R}_{\text{CSO}}} \tag{eq. 4}$$

$$R_{CSO} = \frac{100}{1} \times \frac{2.55}{I_{LIM}}$$
 (eq. 5)

Where

- current limit setting resistor R_{CSO} V_{CSO} - voltage at CSO pin proportional to Iout - current limit value ILIM Iout

- output current actual value

CSO pin provides information about output current actual value. The CSO voltage is proportional to output current according to Equation 3.

Once output current reaches its limit value (ILIM) set by external resistor R_{CSO} than voltage at CSO pin is typically 2.55 V. Calculations of I_{LIM} or R_{CSO} values can be done using equations Equation 4 and Equation 5, respectively.

Thermal Considerations

As power in the NCV47710 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part. When the NCV47710 has good thermal conductivity through the PCB, the junction temperature will be relatively low with high power applications. The maximum dissipation the NCV47710 can handle is given by:

$$\mathsf{P}_{\mathsf{D}(\mathsf{MAX})} = \frac{\left[\mathsf{T}_{\mathsf{J}(\mathsf{MAX})} - \mathsf{T}_{\mathsf{A}}\right]}{\mathsf{R}_{\mathsf{P},\mathsf{J}\mathsf{A}}} \qquad (\mathsf{eq. 6})$$

Since T_J is not recommended to exceed 150°C, then the NCV47710 soldered on 645 mm², 1 oz copper area, FR4 can dissipate up to 1.8 W (SOIC-8 EP) or 1 W (SOIC-8) and up to 4.3 W (SOIC-8 EP) or 1.6 W (SOIC-8) for 4 layers PCB (all layers are 1 oz) when the ambient temperature (T_A) is 25°C. See Figure 18 for RthJA versus PCB area. The power dissipated by the NCV47710 can be calculated from the following equations:

$$\mathsf{P}_{\mathsf{D}} = \mathsf{V}_{\mathsf{in}} \big(\mathsf{I}_{\mathsf{q}} @ \mathsf{I}_{\mathsf{out}} \big) + \mathsf{I}_{\mathsf{out}} \big(\mathsf{V}_{\mathsf{in}} - \mathsf{V}_{\mathsf{out}} \big) \qquad (\mathsf{eq. 7})$$

$$V_{in(MAX)} \approx \frac{P_{D(MAX)} + (V_{out} \times I_{out})}{I_{out} + I_{q}}$$
 (eq. 8)

Hints

or

Vin and GND printed circuit board traces should be as wide as possible. When the impedance of these traces is high, there is a chance to pick up noise or cause the regulator to malfunction. Place external components, especially the output capacitor, as close as possible to the NCV47710 and make traces as short as possible.

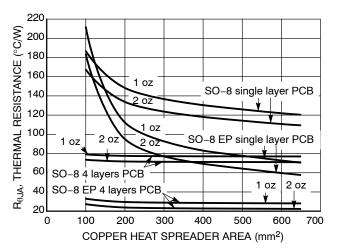


Figure 18. Thermal Resistance vs. PCB Copper Area

ORDERING INFORMATION

Device	Output Voltage	Marking	Package	Shipping [†]
NCV47710PDAJR2G	Adjustable	47710	SOIC-8 EP (Pb-Free)	2500 / Tape & Reel
NCV47710DAJR2G	Adjustable	47710	SOIC-8 (Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

onsemí



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

DOCUMENT NUMBER:	R: 98ASB42564B Electronic versions are uncontrolled except when accessed directly from the Document Repos Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SOIC-8 NB		PAGE 1 OF 2	
the right to make changes without furth purpose, nor does onsemi assume ar	onsemi and ONSEMi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.			

SOIC-8 NB CASE 751-07 **ISSUE AK**

STYLE 1: PIN 1. EMITTER COLLECTOR 2. 3. COLLECTOR 4. EMITTER 5. EMITTER BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT IOUT 6. IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3 P-SOURCE P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE ANODE 2. SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 COMMON ANODE/GND 5. 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4 SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5.

6.

7.

8 GATE 1

SOURCE 1/DRAIN 2

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. DRAIN, #2 4. GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. З. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 MIRROR 1 8. STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. 8. LINE 1 OUT STYLE 27: PIN 1. ILIMIT OVI O 2 UVLO З. 4. INPUT+ 5. 6. SOURCE SOURCE SOURCE 7. 8 DRAIN

DATE 16 FEB 2011

STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 З. BASE #2 COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6 DRAIN DRAIN 7. 8. DRAIN STYLE 16 EMITTER, DIE #1 PIN 1. 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW_TO_GND 2. DASIC OFF DASIC_SW_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

DOCUMENT NUMBER:	98ASB42564B Electronic versions are uncontrolled except when accessed directly from the Document Re Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SOIC-8 NB		PAGE 2 OF 2	

onsem and of isor in are trademarks or semiconductor compension instructions, the do onsem or its subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced stat purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

7.

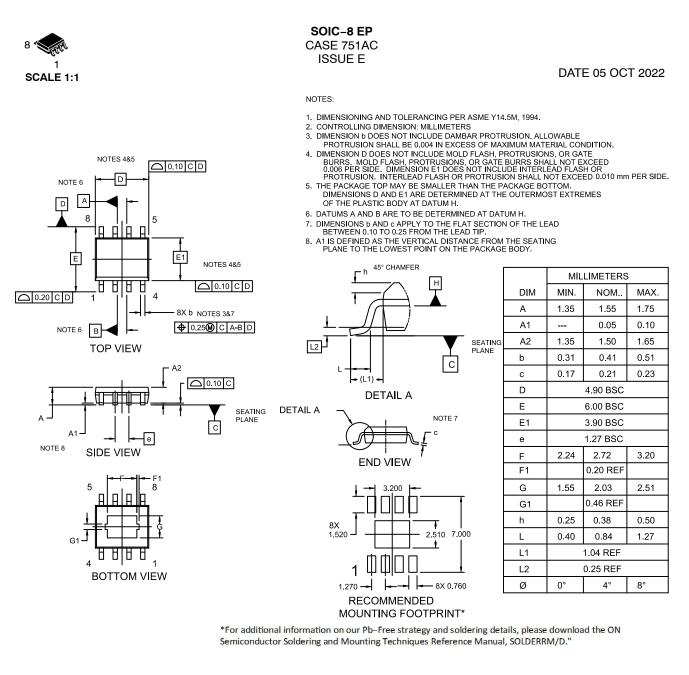
8

COLLECTOR, #1

COLLECTOR, #1

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

DUSEM



GENERIC **MARKING DIAGRAM***

A<u>A</u>B XXXXX AYWW=

XXXXXX	= Specific Device Code
A	= Assembly Location
Y	= Year
WW	= Work Week

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " -", may or may not be present and may be in either location. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON14029D	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOIC-8 EP		PAGE 1 OF 1

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>